

ESD Protection Diode Array, 5-Line

SMS05C, SMS12C, SMS15C, SMS24C

This 5-line surge protection array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single TSOP-6 package.

Features

- Protects up to 5 Lines in a Single TSOP-6 Package
- Peak Power Dissipation 350 W (8 × 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8.0 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8.0 kV (Contact)
- Flammability Rating of UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation 8 \times 20 μs Double Exponential Waveform (Note 1)	350	W
T_J	Operating Junction Temperature Range	-40 to 150	°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
T_L	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	>8000 >400 >15000 >8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

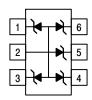
1. Non-repetitive current pulse per Figure 3.

TSOP-6 FIVE SURGE PROTECTION 350 W PEAK POWER

PIN ASSIGNMENT



CASE 318G SCALE 2:1



PIN 1. CATHODE

- ANODE
- 3. CATHODE
- 4. CATHODE
- 5. CATHODE
- 6. CATHODE

MARKING DIAGRAM



s = SMS05C:J

= SMS12C:K

= SMS15C:L = SMS24C:M

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
SMS05CT1G		
SMS12CT1G	TSOP-6	3000 / Tape & Reel
SMS15CT1G	(Pb-Free)	3000 / Tape & neer
SMS24CT1G SZSMS24CT1G		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

SMS05C, SMS12C, SMS15C, SMS24C

SMS05C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V_{BR}	I _T = 1.0 mA (Note 3)	6.2		7.2	V
Reverse Leakage Current	I _R	V _{RWM} = 5.0 V			5.0	μΑ
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 \times 20 μ s Waveform)			9.8	V
Clamping Voltage	V _C	I _{PP} = 24 A (8 × 20 μs Waveform)			14.5	V
Maximum Peak Pulse Current	I _{PP}	$8 \times 20~\mu s$ Waveform			24	Α
Capacitance	CJ	V _R = 0 V, f = 1.0 MHz (Line to GND)		260	400	pF

SMS12C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			12	V
Breakdown Voltage	V_{BR}	I _T = 1.0 mA (Note 3)	13.3		15	V
Reverse Leakage Current	I _R	V _{RWM} = 12 V		0.001	1.0	μΑ
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 \times 20 μ s Waveform)			19	V
Clamping Voltage	V _C	I _{PP} = 15 A (8 × 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			15	Α
Capacitance	CJ	V _R = 0 V, f = 1.0 MHz (Line to GND)		120	150	pF

SMS15C ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$, unless otherwise specified) (See Note 4)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			15	V
Breakdown Voltage	V_{BR}	I _T = 1.0 mA (Note 3)	17		19	V
Reverse Leakage Current	I _R	V _{RWM} = 15 V		0.05	1.0	μΑ
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 $ imes$ 20 μ s Waveform)			24	V
Clamping Voltage	V _C	I_{PP} = 12 A (8 × 20 μ s Waveform)			29	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			12	Α
Capacitance	CJ	V _R = 0 V, f = 1.0 MHz (Line to GND)		95	125	pF

SZ/SMS24C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

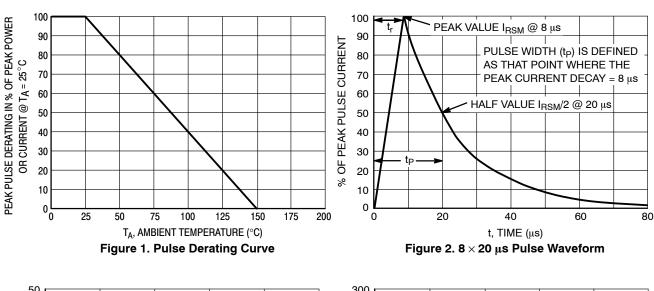
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			24	V
Breakdown Voltage	V_{BR}	I _T = 1.0 mA (Note 3)	26.7		32	V
Reverse Leakage Current	I _R	V _{RWM} = 24 V		0.001	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 5.0 A (8 × 20 μs Waveform)			40	V
Clamping Voltage	V _C	I _{PP} = 8 A (8 × 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			8.0	Α
Capacitance	CJ	V _R = 0 V, f = 1.0 MHz (Line to GND)		60	75	pF

^{2.} Surge protection devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

^{3.} V_{BR} is measured at pulse test current I_T.
4. Parametrics are the same for the Pb–Free packages, which are suffixed with a "G".

SMS05C, SMS12C, SMS15C, SMS24C

TYPICAL PERFORMANCE CURVES (T_{.J} = 25°C unless otherwise specified)



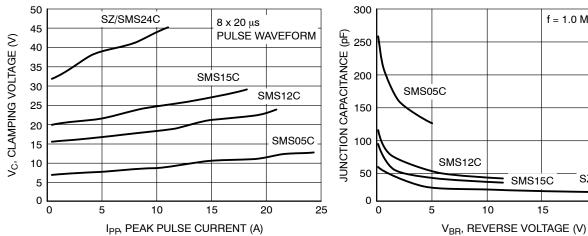


Figure 3. Clamping Voltage vs. Peak Pulse Current

(8.0 kV Contact)

Figure 4. Junction Capacitance vs. Reverse Voltage

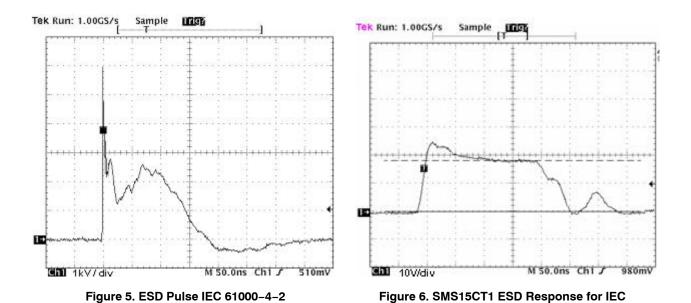
61000-4-2 (+8.0 kV Contact)

f = 1.0 MHz

SZ/SMS24C

25

20



www.onsemi.com

SMS05C, SMS12C, SMS15C, SMS24C

TYPICAL COMMON ANODE APPLICATIONS

A 5 surge protection junction common anode design in a TSOP-6 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design

especially when board space is at a premium. A simplified example of SMS05C Series Device applications is illustrated below.

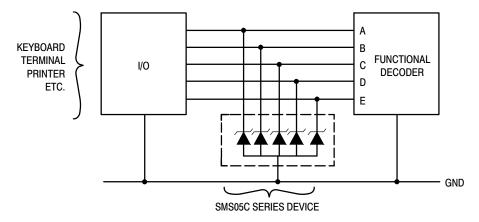


Figure 7. Computer Interface Protection

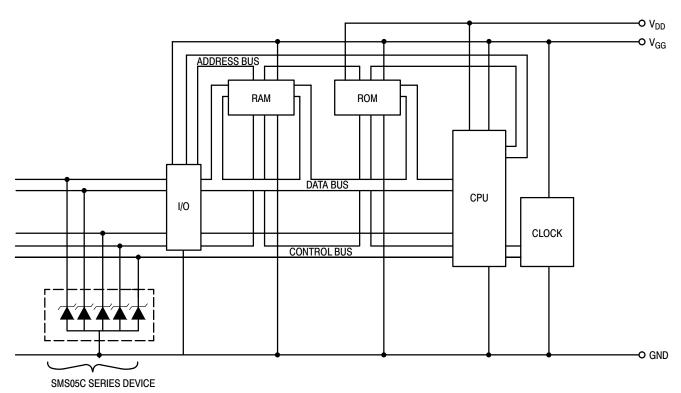


Figure 8. Microprocessor Protection



TSOP-6 CASE 318G-02 **ISSUE V**

12

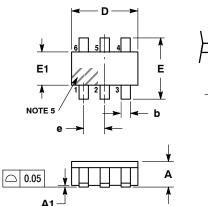
C SEATING PLANE

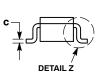
DATE 12 JUN 2012

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D
- AND E1 ARE DETERMINED AT DATUM H.
 PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	0.90	1.00	1.10		
A1	0.01	0.06	0.10		
b	0.25	0.38	0.50		
С	0.10	0.18	0.26		
D	2.90	3.00	3.10		
E	2.50	2.75	3.00		
E1	1.30	1.50	1.70		
е	0.85	0.95	1.05		
L	0.20	0.40	0.60		
L2	0.25 BSC				
М	0°	_	10°		





DETAIL Z

Н

STYLE 1: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN	STYLE 2: PIN 1. EMITTE 2. BASE 1 3. COLLEC 4. EMITTE 5. BASE 2 6. COLLEC
STYLE 7: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. N/C 5. COLLECTOR 6. EMITTER	STYLE 8: PIN 1. Vbus 2. D(in) 3. D(in)+ 4. D(out)+ 5. D(out) 6. GND





6.	V out	
2.	LOW VOLTAGE GATE DRAIN	
3.	SOURCE	



STYLE 10: PIN 1. D(OUT)+	STY PIN
2. GND [']	
D(OUT)-	
4. D(IN)-	
5. VBUS	
D(IN)+	

3. NOT USED 4. GROUND

5. ENABLE 6. LOAD

/LE 11: N 1. SOURCE 1 2. DRAIN 2 DRAIN 2 4 SOURCE 2 5. GATE 1 6. DRAIN 1/GATE 2

STYLE 5: PIN 1. EMITTER 2 2. BASE 2

3. COLLECTOR 1 4. EMITTER 1

6. COLLECTOR 2

BASE 1

3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR STYLE 12: 2. GROUND 3. I/O 4. I/O

5. VCC 6. I/O

STYLE 6: PIN 1. COLLECTOR 2. COLLECTOR

STYLE 1	3:
PIN 1.	GATE 1
2.	SOURCE
3.	GATE 2
4.	DRAIN 2



STYLE 15: PIN 1. ANODE

SOURCE
GATE
DRAIN
N/C
CATHODE

STYLE 16: PIN 1. ANODE/CATHODE 2. BASE FMITTER 3

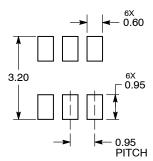
STYLE 4: PIN 1. N/C 2. V in

COLLECTOR 5. ANODE CATHODE

STYLE 17: PIN 1. EMITTER 2. BASE 3 ANODE/CATHODE

CATHODE COLLECTOR

RECOMMENDED **SOLDERING FOOTPRINT***



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*





XXX = Specific Device Code Α =Assembly Location

Υ = Year

W = Work Week = Pb-Free Package XXX = Specific Device Code M

= Date Code = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present.

DOCUMENT NUMBER:	98ASB14888C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TSOP-6		PAGE 1 OF 1

ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative